## NJM4558/4559

The NJM4558/4559 integrated circuit are a dual high-gain operational amplifier internally compensated and constru -cted on a single silicon chip using an advanced epitaxial process.

Combining the features of the NJM741 with the close parameter matching and tracking of a dual device on a mono -lithic chip results in unique performance characteristics. Excellent channel separation allow the use of the dual device in single NJM741 operational amplifier applications providing density. It is especially well suited for applications in di -fferential-in, differential-out as well as in potentiometric amplifiers and where gain and phase matched channels are ma -ndatory.

- Package Outline
- Absolute Maximum Ratings ( $\mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Supply Voltage | $\mathrm{V}^{+} / \mathrm{V}^{-}$ | $\pm 18 \mathrm{~V}$ |
| :--- | :--- | :--- |
| Differential Input Voltage | $\mathrm{V}_{\mathrm{ID}}$ | $\pm 30 \mathrm{~V}$ |
| Input Voltage (note) | $\mathrm{V}_{\mathrm{I}}$ | $\pm 15 \mathrm{~V}$ |
| Power Dissipation | $\mathrm{P}_{\mathrm{D}}$ (D-Type) | 500 mW |
|  | (M,V-Type) | 300 mW |
|  | (L-Type) | 800 mw |
| Operating Temperature Range | $\mathrm{T}_{\text {opr }}$ | $-20 \sim+75^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\mathrm{sIg}}$ | $-40 \sim+125^{\circ} \mathrm{C}$ |
|  |  |  |
| (note) | For supply voltage less than +15 V, the absolute maximum |  |
| input voltage is equal to the supply voltage. |  |  |



Electrical Characteristics ( $\mathrm{V}^{+} / \mathrm{V}-= \pm 15 \mathrm{~V}, \mathrm{Ta} 25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Test Condition | Min. | Typ. | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input Offset Voltage | $\mathrm{V}_{10}$ | $\mathrm{R}_{\mathrm{s}} \leqq 10 \mathrm{k} \Omega$ | - | 0.5 | 6 | mV |
| Input Offset Current | $\mathrm{I}_{10}$ |  | - | 5 | 200 | nA |
| Input Bias Current | $\mathrm{I}_{\mathrm{B}}$ |  | - | 25 | 500 | nA |
| Input Resistance | $\mathrm{R}_{\text {IN }}$ |  | 0.3 | 5 | - | $\mathrm{M} \Omega$ |
| Large Signal Voltage Gain | $\mathrm{A}_{\mathrm{y}}$ | $\mathrm{R}_{\mathrm{L}} \geqq 2 \mathrm{k} \Omega, \mathrm{V}_{\mathrm{O}}= \pm 10 \mathrm{~V}$ | 86 | 100 | - | dB |
| Maximum Output Voltage Swing 1 | $\mathrm{V}_{\text {OM1 }}$ | $\mathrm{R}_{\mathrm{L}} \geqq 10 \mathrm{k} \Omega$ | $\pm 12$ | $\pm 14$ | - | V |
| Maximum Output Voltage Swing 2 | $\mathrm{V}_{\text {OM2 }}$ | $\mathrm{R}_{\mathrm{L}} \geqq 2 \Omega$ | $\pm 10$ | $\pm 13$ | - | V |
| Input Common Mode Voltage Range | VICM |  | $\pm 12$ | 14 | - | V |
| Common Mode Rejection Ratio | CMR | $\mathrm{Rs} \leqq 10 \mathrm{k} \Omega$ | 70 | 90 | - | dB |
| Supply Voltage Rejection Ratio | SVR | RS $\leqq 10 \mathrm{k} \Omega$ | 76.5 | 90 | - | dB |
| Supply Current | $\mathrm{I}_{C C}$ |  | - | 3.5 | 5.7 | mA |
| Slew Rate |  |  |  |  |  |  |
| NJM4558 | SR |  | - | 1 | - | $\mathrm{V} / \mu \mathrm{S}$ |
| JM4559 | SR |  | - | 2 | - | $\mathrm{V} / \mu \mathrm{S}$ |
| Equivalent Input Noise Voltage | $\mathrm{V}_{\mathrm{NI}}$ | RIAA, $\mathbf{R S}_{\mathbf{S}}=1 \mathrm{k} \Omega, 30 \mathrm{kHz}$ LPF | - | 1.4 | - | $\mu \mathrm{Vrms}$ |
| Unity Gain Bandwidth | GB |  |  |  |  |  |
| NJM4558 |  |  |  | 3 |  | MHz |
| NJM4559 |  |  |  | 6 |  | MHz |

Equivalent Circuit (1/2 Shown)


## - Connection Diagram

D,M,V-Type


L-Type


## - Typical Characteristics



## Supply Current vs. Temperature



Maximum Output Voltage Swing
vs. Temperature


## - Typical Characteristics



Input Bias Current vs. Temperature


Maximum Output Voltage Swing
vs. Supply Voltage
( $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \quad \mathrm{Ta}=25^{\circ} \mathrm{C}$ )


## Supply Current vs. Supply Voltage



